NSN 5961-01-049-8368

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Inclosure Material:

Metal

Overall Length:

0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

Internal Configuration:

Field effect

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 60.0 breakdown voltage, gate-to-source,

with all other terminals short-circuited to source and 60.0 reverse gate to source voltage

Current Rating Per Characteristic:

20.00 milliamperes drain current and 10.00 milliamperes gate current

Power Rating Per Characteristic:

200.0 milliwatts total device dissipation

Test Data Document:

77327-40704 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0